Diode Semiconductor Device - Page 1 of 1



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Inclosure Ma	terial:
Metal	
Overall Lengt	th:
0.260 inches	
Terminal Len	ngth:
1.500 inches	
Overall Diam	eter:
0.370 inches	
Function For	Which Designed:
Current regula	ator
Electrode Inte	ernally-electrically Connected To Case:
Gate	
Mounting Me	thod:
Terminal	
Semiconduct	tor Material:
Silicon	
Voltage Ratin	ng In Volts Per Characteristic:
6.0 limiting vo	bltage
Current Ratin	ng Per Characteristic:
18.00 milliamp	peres service voltage pascal and 22.00 milliamperes source cutoff current pascal
Power Rating	g Per Characteristic:
1.5 watts sma	Il-signal input power, common-collector absolute
Maximum Op	perating Tempurature Per Measurement Point:
200.0 degrees	s celsius junction
Test Data Do	cument:
95105-204-00	15 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any	specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Typ	e And Quantity:
2 uninsulated	wire lead
Shelf Life:	
N/a	
Unit Of Meas	ure:
Demilitarizati	ion:
No	
Fiig:	
A110a0	